
	<h2 style="color: red;">FDMA905P_F130</h2>
 <p>Not Actual Photo YIC International Co., Limited.</p>	<p>Hersteller-Teilenummer: FDMA905P_F130</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

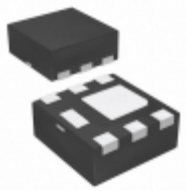
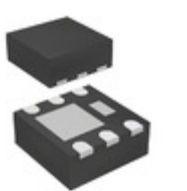
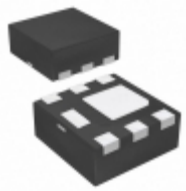
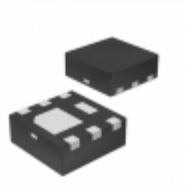
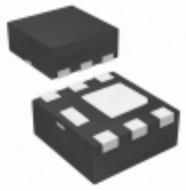
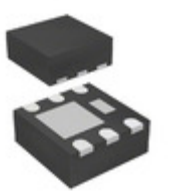
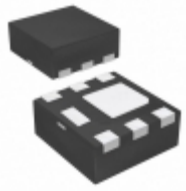
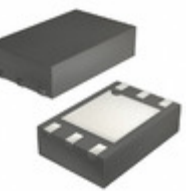
Spezifikationen

Teilenummer	FDMA905P_F130
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	1V @ 250µA
Vgs (Max)	±8V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	6-MicroFET (2x2)
Serie	PowerTrench®
Rds On (Max) @ Id, Vgs	16 mOhm @ 10A, 4.5V
Verlustleistung (max)	2.4W (Ta)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	6-VDFN Exposed Pad
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Eingabekapazität (Ciss) (Max) @ Vds	3405pF @ 6V
Gate Charge (Qg) (Max) @ Vgs	29nC @ 6V
Typ FET	P-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Drain-Source-Spannung (Vdss)	12V
detaillierte Beschreibung	P-Channel 12V 10A (Ta) 2.4W (Ta) Surface Mount 6-
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Ta)

FDMA905P_F130 Electronic Components ist ein 100% neues Original von YIC Distributor, FDMA905P_F130-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, FDMA905P_F130 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ FDMA905P_F130 E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>FDMA905P AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 6-MLP 2X2</p>	 <p>FDMA8884 Fairchild/ON Semiconductor MOSFET N-CH 30V 6.5A 6-MLP 2X2</p>	 <p>FDMA910PZ AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 9.4A MICROFET</p>	 <p>FDMA908PZ Fairchild/ON Semiconductor MOSFET P-CH 12V 12A 6QFN</p>
 <p>FDMA910PZ Fairchild/ON Semiconductor MOSFET P-CH 20V 9.4A MICROFET</p>	 <p>FDMA8884 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6.5A 6-MLP 2X2</p>	 <p>FDMA905P Fairchild/ON Semiconductor MOSFET P-CH 12V 6-MLP 2X2</p>	 <p>FDMB2307NZ Fairchild/ON Semiconductor MOSFET 2N-CH 6-MLP</p>

Verwandtes Hot-Keyword

Mehr

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FDMA905P_F130 Electronic	FDMA905P_F130-Komponenten	FDMA905P_F130-Bild	FDMA905P_F130-Teil
FDMA905P_F130 Preis	FDMA905P_F130 Hersteller	FDMA905P_F130 Aktie	FDMA905P_F130 Inventar
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Contact us: Info@Y-IC.com

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